

DLP120-24-1

RELIABILITY DATA

DWG No. CA734-57-01			
QA APPD	APPD	CHK	DWG
<i>T. Murayama</i> 4/Jun/'03	<i>fts</i> 30-May- 2003	<i>[Signature]</i> 30/May/03	<i>Xie</i> 26/May/03

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※ The above data is typical value. As all units have nearly the same characteristics, the data to be considered as ability value.

1. CALCULATED VALUES OF MTBF

MODEL : DLP120-24-1

(1) Calculating method

Calculated based on part count reliability projection of JEITA (RCR-9102).

Individual failure rates λ_G is given to each part and MTBF is calculated by the count of each part.

<Formula> :

$$MTBF = \frac{1}{\lambda_{\text{equip}}} = \frac{1}{\sum_{i=1}^n N_i (\lambda_G \pi_Q)_i} \times 10^6 \text{ (Hours)}$$

λ_{equip} : Total Equipment Failure Rate (Failure/10⁶ Hours)

λ_G : Generic Failure Rate for The ith Generic Part (Failure/10⁶ Hours)

N_i : Quantity of ith Generic Part

n : Number of Different Generic Part Categories

π_Q : Generic Quality Factor for The ith Generic Part ($\pi_Q = 1$)

(2) MTBF Values

G_F : (Ground , Fixed)

MTBF ≒ 373,095 (Hours)

2. COMPONENT DERATING

MODEL DLP120-24-1

(1) Calculating Method

(a) Measuring Conditions

- Input : 100VAC • Ambient temperature : 50°C
- Output : 24V 5A(100%) • Mounting method : Standard Mounting

(b) Semiconductors

Compared with maximum junction temperature and actual one which is calculated based on case temperature, power dissipation and thermal impedance.

(c) IC, Resistors, Capacitors, etc.

Ambient temperature, operating condition, power dissipation and so on are within derating criteria.

(d) Calculating Method of Thermal Impedance

$$\theta_{j-c} = \frac{T_{j(max)} - T_c}{P_{c(max)}} \quad \theta_{j-a} = \frac{T_{j(max)} - T_a}{P_{c(max)}} \quad \theta_{j-l} = \frac{T_{j(max)} - T_l}{P_{c(max)}}$$

T_c : Case Temperature at Start Point of Derating ; 25°C in General

T_a : Ambient Temperature at Start Point of Derating ; 25°C in General

T_l : Lead Temperature at Start Point of Derating ; 25°C in General

$P_{c(max)}$
($P_{ch(max)}$) : Maximum Collector(channel) Dissipation

$T_{j(max)}$
($T_{ch(max)}$) : Maximum Junction(channel) Temperature

θ_{j-c}
(θ_{ch-c}) : Thermal Impedance between Junction(channel) and Case

θ_{j-a} : Thermal Impedance between Junction and Air

θ_{j-l} : Thermal Impedance between Junction and Lead

(2) Component Derating List

Location No.	Vin = 100VAC	Load = 100%	Ta = 50°C
Q1 2SK2611 TOSHIBA	Tchmax = 150 °C, Pch = 4.68W, Tch = Tc + ((θ ch-c) × Pch) = 87.3 °C D.F. = 58.2%	θ ch-c = 0.833 °C/W, Δ Tc = 33.4 °C,	Pch(max) = 150 W, Tc = 83.4°C
D1 DS3B60 SHINDENGEN	Tjmax = 150 °C, Pd = 1.2W, Tj = Tc + ((θ j-c) × Pd) = 95.7°C D.F. = 63.8%	θ j-c = 5.5 °C/W, Δ Tc = 39.1 °C,	Tc = 89.1 °C
D51 ESAD92M-02R FUJI-ELE.	Tjmax = 150 °C, Pd = 4.75 W, Tj = Tc + ((θ j-c) × Pd) = 137.2 °C D.F. = 91.5%	θ j-c = 2 °C/W, Δ Tc = 77.7°C,	Tc = 127.7 °C
Q101 2SC3075 TOSHIBA	Tjmax = 150 °C, Pd = 0W, Tj = Ta + ((θ j-c) × Pd) = 88.7°C D.F. = 59.1%	θ j-c = 12.5 °C/W, Δ Ta = 38.7 °C,	Pd(max) = 1 W, Ta = 88.7°C
Q102 HN1B01F-Y SHINDENGEN	Tjmax = 125 °C, Pd = 25 mW, Tj = Ta + ((θ j-a) × Pd) = 88.7 °C D.F. = 71.0%	θ j-a = 333 °C/W, Δ Ta = 30.4°C,	Pd(max) = 300m W, Ta = 80.4 °C
Q103 2SC3075 TOSHIBA	Tjmax = 150 °C, Pd = 0.75W, Tj = Ta + ((θ j-c) × Pd) = 105.6 °C D.F. = 70.4%	θ j-c = 12.5 °C/W, Δ Ta = 46.2 °C,	Pd(max) = 1 W, Ta = 96.2 °C
Q301 2SC2712 TOSHIBA	Tjmax = 125 °C, Pd = 9mW, Tj = Ta + ((θ j-a) × Pd) = 95.7°C D.F. = 76.6%	θ j-a = 667 °C/W, Δ Ta = 39.7 °C,	Pd(max) = 150mW, Ta = 89.7°C
D101 U05NU44 TOSHIBA	Tjmax = 150 °C, Pd = 14.5mW, Tj = Ta + ((θ j-a) × Pd) = 89.4 °C D.F. = 59.6%	θ j-a = 110 °C/W, Δ Ta = 37.8 °C,	Ta = 87.8 °C
D102 CRH01 SHINDENGEN	Tjmax = 150 °C, Pd = 0 W, Tj = Ta + ((θ j-a) × Pd) = 88.3 °C D.F. = 58.9%	θ j-a = 130 °C/W, Δ Ta = 38.3 °C,	Ta = 88.3 °C
D103 CRH01 TOSHIBA	Tjmax = 150 °C, Pd = 0.076 W, Tj = Ta + ((θ j-a) × Pd) = 104.8 °C D.F. = 69.9%	θ j-a = 130 °C/W, Δ Ta = 54.9 °C,	Ta = 94.9 °C
D301 CRH01 TOSHIBA	Tjmax = 150 °C, Pd = 0.083 W, Tj = Ta + ((θ j-a) × Pd) = 123.7°C D.F. = 82.5%	θ j-a = 130 °C/W, Δ Ta = 62.9°C,	Ta = 112.9 °C
D302 1SS184-TE85L TOSHIBA	Tjmax = 150 °C, Pd = 5.8 mW, Tj = Ta + ((θ j-a) × Pd) = 89.7 °C D.F. = 59.8%	θ j-a = 667°C/W, Δ Ta = 35.8 °C,	Pd(max) = 150 mW Ta = 85.8 °C
Z101 02CZ11-X TOSHIBA	Tjmax = 150 °C, Pd = 0 mW, Tj = Ta + ((θ j-a) × Pd) = 78.7 °C D.F. = 52.5%	θ j-a = 625 °C/W, Δ Ta = 28.7 °C,	Pd(max) = 200mW Ta = 78.7 °C
Z102 02CZ5.6-Y TOSHIBA	Tjmax = 150 °C, Pd = 0 mW, Tj = Ta + ((θ j-a) × Pd) = 75.8 °C D.F. = 50.5%	θ j-a = 625 °C/W, Δ Ta = 25.8 °C,	Pd(max) = 200mW Ta = 75.8 °C
Z103 U1ZB27 TOSHIBA	Tjmax = 150 °C, Pd = 0 mW, Tj = Ta + ((θ j-a) × Pd) = 89.2 °C D.F. = 59.5%	θ j-a = 125 °C/W, Δ Ta = 39.2 °C,	Pd(max) = 1W Ta = 89.2 °C

Location No.	$V_{in} = 100VAC$	Load = 100%	$T_a = 50^{\circ}C$
Z201 MA3330-L-TX MATSUSHITA	$T_{jmax} = 150^{\circ}C$, $P_d = 0mW$, $T_j = T_a + ((\theta_{j-a}) \times P_d) = 98.4^{\circ}C$ D.F. = 65.6%	$\theta_{j-a} = 625^{\circ}C/W$, $\Delta T_a = 48.4^{\circ}C$,	$P_d(max) = 200mW$ $T_a = 98.4^{\circ}C$
Z301 02C218-V TOSHIBA	$T_{jmax} = 150^{\circ}C$, $P_d = 9.9mW$, $T_j = T_a + ((\theta_{j-a}) \times P_d) = 99.9^{\circ}C$ D.F. = 66.6%	$\theta_{j-a} = 625^{\circ}C/W$, $\Delta T_a = 43.7^{\circ}C$,	$P_d(max) = 200mW$ $T_a = 93.7^{\circ}C$
PC101 PS2581L2-E3 (LED) TOSHIBA	$T_{jmax} = 125^{\circ}C$, $I_d = 0mA$, ALLOWABLE $I_F(max) = 52.0mA$ (at $T_a = 95.1^{\circ}C$) D.F. = 0%	$\theta_{j-a} = 667^{\circ}C/W$, $\Delta T_a = 45.1^{\circ}C$,	$P_d(max) = 150mW$, $T_a = 95.1^{\circ}C$
PC101 PS2581L2-E3 (Transistor) TOSHIBA	$T_{jmax} = 125^{\circ}C$, $P_d = 0mW$, $I_j = I_a + ((\theta_{j-a}) \times P_d) = 95.1^{\circ}C$ D.F. = 76.1%	$\theta_{j-a} = 667^{\circ}C/W$, $\Delta T_a = 45.1^{\circ}C$,	$P_c(max) = 150mW$, $T_a = 95.1^{\circ}C$
PC102 PS2581L2-E3 (LED) TOSHIBA	$T_{jmax} = 125^{\circ}C$, $I_d = 1.2mA$, ALLOWABLE $I_F(max) = 52.0mA$ (at $T_a = 91.1^{\circ}C$) D.F. = 3.75%	$\theta_{j-a} = 667^{\circ}C/W$, $\Delta T_a = 41.1^{\circ}C$,	$P_d(max) = 150mW$, $T_a = 91.1^{\circ}C$
PC102 PS2581L2-E3 (Transistor) TOSHIBA	$T_{jmax} = 125^{\circ}C$, $P_d = 20mW$, $T_j = T_a + ((\theta_{j-a}) \times P_d) = 104.4^{\circ}C$ D.F. = 83.5%	$\theta_{j-a} = 667^{\circ}C/W$, $\Delta T_a = 41.1^{\circ}C$,	$P_c(max) = 150mW$, $T_a = 91.1^{\circ}C$
A101 M51995AFP-600C MITSUBISHI	$T_{jmax} = 150^{\circ}C$, $P_d = 0.274W$, $T_j = T_c + ((\theta_{j-c}) \times P_d) = 110.7^{\circ}C$ D.F. = 73.8%	$\theta_{j-c} = 40^{\circ}C/W$, $\Delta T_c = 49.7^{\circ}C$,	$P_d(max) = 1.5W$ $T_c = 99.7^{\circ}C$
A401 μ PC1093-E1 NEC	$T_{jmax} = 150^{\circ}C$, $P_d = 30mW$, $T_j = T_a + ((\theta_{j-a}) \times P_d) = 104.2^{\circ}C$ D.F. = 69.5%	$\theta_{j-a} = 315^{\circ}C/W$, $\Delta T_a = 44.7^{\circ}C$,	$P_d(max) = 400mW$ $T_a = 94.7^{\circ}C$
SR1 SM8JZ47A NEC	$T_{jmax} = 125^{\circ}C$, $P_d = 1.8W$, $T_j = T_c + ((\theta_{j-c}) \times P_d) = 99.5^{\circ}C$ D.F. = 79.6%	$\theta_{j-c} = 3.6^{\circ}C/W$, $\Delta T_c = 43^{\circ}C$,	$T_c = 93^{\circ}C$

3. MAIN COMPONENTS TEMPERATURE RISE ΔT LIST

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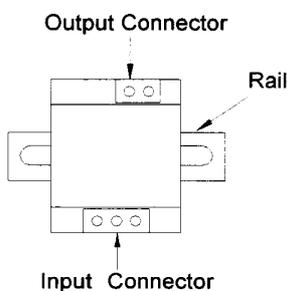
Measuring Conditions

Mounting Method (Standard Mounting)		
Input Voltage (VAC)		100
Output Voltage (VDC)		24
Output Current (A)		5

※ Condition $T_a = 50^\circ\text{C}$, Convection cooling .

Output Derating (100%) $T_a = 50^\circ\text{C}$		Standard Mounting
Location No.	Parts Name	ΔT Temperature rise ($^\circ\text{C}$)
L1	BALUN COIL	48.6
L2	BALUN COIL	46.5
L51	CHOKE COIL	54.1
D1	BRIDGE DIODE	40.6
D2	DIAC	28.7
D51	LLD	77.7
Q1	MOS FET	34.5
T1	TRANS PULSE	65.1
A101	CHIP IC	47.8
A401	CHIP IC	44.7
C5	E. CAP.	23.9
C6	E. CAP.	29.7
C7	E. CAP.	20.0
C10	E. CAP.	39.0
C51	E. CAP.	39.9
C52	E. CAP.	37.8
C54	E. CAP.	44.2

Measuring Conditions

Mounting Method (Standard Mounting)		
Input Voltage (VAC)	230	
Output Voltage (VDC)	24	
Output Current (A)	5	

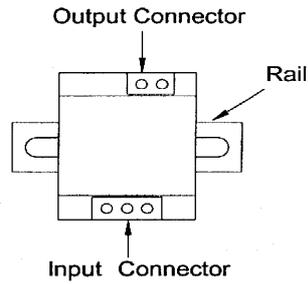
※ Condition Ta = 50°C , Convection cooling .

Output Derating (100%) Ta = 50°C		Standard Mounting
Location No.	Parts Name	ΔT Temperature rise (°C)
L1	BALUN COIL	31.2
L2	BALUN COIL	30.4
L51	CHOKE COIL	53.4
D1	BRIDGE DIODE	37.5
D2	DIAC	21.8
D51	LLD	78.2
Q1	MOS FET	37.1
T1	TRANS PULSE	65.1
A101	CHIP IC	51.9
A401	CHIP IC	41.8
C5	E. CAP.	24.7
C6	E. CAP.	29.8
C7	E. CAP.	18.2
C10	E. CAP.	40.0
C51	E. CAP.	36.2
C52	E. CAP.	32.6
C54	E. CAP.	41.7

4. ELECTROLYTIC CAPACITOR LIFETIME

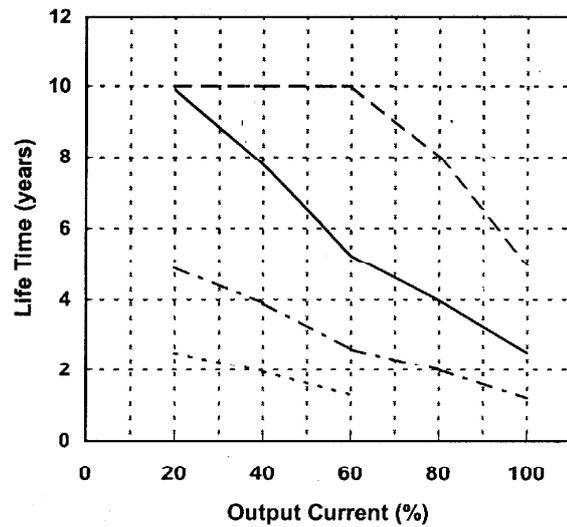
MODEL: DLP120-24-1

Standard Mounting



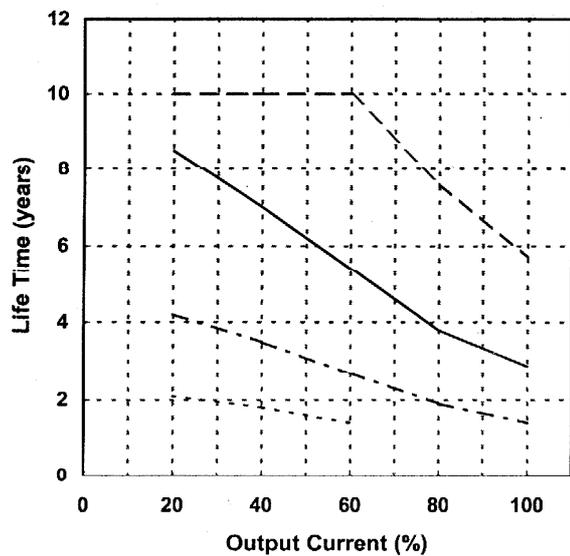
$V_{in} = 100VAC$

Load (%)	Life Time (years)			
	Ta = 30°C	Ta = 40°C	Ta = 50°C	Ta = 60°C
20	10.0	9.9	4.9	2.5
40	10.0	7.8	3.9	2.0
60	10.0	5.3	2.6	1.3
80	8.0	4.0	2.0	---
100	5.0	2.5	1.2	---



$V_{in} = 230VAC$

Load (%)	Life Time (years)			
	Ta = 30°C	Ta = 40°C	Ta = 50°C	Ta = 60°C
20	10.0	8.5	4.2	2.1
40	10.0	7.0	3.5	1.8
60	10.0	5.4	2.7	1.4
80	7.6	3.8	1.9	---
100	5.7	2.9	1.4	---



Ta = 30°C
 Ta = 40°C ——
 Ta = 50°C - - - -
 Ta = 60°C - . - . -

5. ABNORMAL TEST

MODEL : DLP120-24-1

(1) Conditions

Input : 230VAC

Output : 24V / 5A

Ta : 25°C , 70%RH

(2) Test Results

(Da : Damaged)

No.	Test position		Test Mode		Test Results												Note
	Location No.	Test Point	Short	Open	1	2	3	4	5	6	7	8	9	10	11	12	
					Fire	Smoke	Burst	Smell	Red Hot	Damaged	Fuse Blown	OVP	OCP	No Output	No Change	Others	
1	Q1	D-G	O						O	O			O		O	Da : Z103,A101,Q1,D102	
2		D-S	O						O	O			O		O	Da : D102	
3		G-S	O											O			
4		D		O										O			
5		S		O										O			
6		G		O						O	O			O		O	Da:Q1,D102
7	A101	1-2	O						O				O		O	R148,R149 OPEN	
8		2-3	O										O				
9		3-4	O												O		
10		4-5	O												O		
11		5-6	O												O		
12		6-7	O												O		
13		7-8	O												O		
14		8-9	O												O		
15		9-10	O											O			
16		11-12	O											O			
17		12-13	O													O	HICCUP
18		13-14	O												O		
19		14-15	O												O		
20		15-16	O												O		
21		16-17	O												O		
22		17-18	O												O		
23		18-19	O												O		
24		19-20	O											O			
25		1		O										O			
26		2		O						O	O			O		O	Da:Z103,Q1
27		3		O										O			

No.	Test position		Test Mode		Test Results												Note
	Location No.	Test Point	Short	Open	1	2	3	4	5	6	7	8	9	10	11	12	
					Fire	Smoke	Burst	Smell	Red Hot	Damaged	Fuse Blown	OVP	OCP	No Output	No Change	Others	
28	A101	4		O											O		
29		5		O											O		
30		6		O											O		
31		7		O											O		
32		8		O											O		
33		9		O											O		
34		10		O								O		O			
35		11		O										O			
36		12		O										O			
37		13		O									O			O O/P LOW	
38		14		O											O		
39		15		O											O		
40		16		O											O		
41		17		O										O			
42		18		O											O		
43		19		O										O			
44		20		O										O			
45	A401	K-A	O												O	O/P LOW	
46		K-R	O												O	O/P LOW	
47		R-A	O									O		O			
48		K		O								O		O			
49		A		O								O		O			
50		R		O								O		O			
51	PC101	1-2	O											O			
52		3-4	O									O		O			
53		1		O											O		
54		2		O											O		
55		3		O											O		
56	4		O											O			
57	PC102	1-2	O								O		O				
58		3-4	O										O				
59		1		O								O		O			
60		2		O								O		O			
61		3		O								O		O			
62		4		O								O		O			

No.	Test position		Test Mode		Test Results												Note	
	Location No.	Test Point	Short	Open	1	2	3	4	5	6	7	8	9	10	11	12		
					Fire	Smoke	Burst	Smell	Red Hot	Damaged	Fuse Blown	OVP	OCP	No Output	No Change	Others		
63	D1	ONE DIODE	O								O			O				
64		ONE LEAD		O											O			
65	D2		O													O		
66				O												O		
67	D101		O							O							O	Da:R126,R127
68				O													O	
69	D102		O														O	
70				O													O	
71	D103		O											O				
72				O													O	HICCUP
73	D301		O											O				
74				O													O	PD51 OFF
75	D302		O														O	PD52 ON
76				O													O	
77	D51	RECTIFIER	O										O				O	HICCUP
78		FREEWHEEL	O										O				O	HICCUP
79		RECTIFIER		O										O				
80		FREEWHEEL		O										O				
81		BOTH		O										O				
82	Q101	C-E	O													O		
83		C-B	O													O		
84		B-E	O													O		
85		C		O												O		
86		E		O												O		
87		B		O												O		
88	Q103	C-E	O							O							O	Da:Q103,Q102,Z102, R138,R126,R127,R144
89		C-B	O							O							O	Da:Q103,Q102,Z102, R126,R127, R144
90		B-E	O													O		
91		C		O												O		
92		E		O												O		
93		B		O												O		
94		Z101		O													O	
95				O												O		
96	Z102		O													O		
97				O												O		

No.	Test position		Test Mode		Test Results												Note	
	Location No.	Test Point	Short	Open	1	2	3	4	5	6	7	8	9	10	11	12		
					Fire	Smoke	Burst	Smell	Red Hot	Damaged	Fuse Blown	CVP	CCP	No Output	No Change	Others		
98	Z103		O											O				
99				O												O		
100	Z201		O									O		O				
101				O												O		
102	Z301		O												O			
103				O											O			
104	C5(C6)		O												O			
105				O													O	HICCUP
106	C7		O															O
107				O						O					O			Da:R126,R127
108	C10		O											O				
109				O										O				
110	C51(C54)		O										O				O	HICCUP
111				O											O			
112	SR1	1-2	O												O			
113		2-3	O							O							O	
114		1		O													O	
115		2		O													O	
116		3		O													O	

6. VIBRATION TEST

MODEL : DLP120-24-1

(1) Vibration Test Class

Frequency Variable Endurance Test

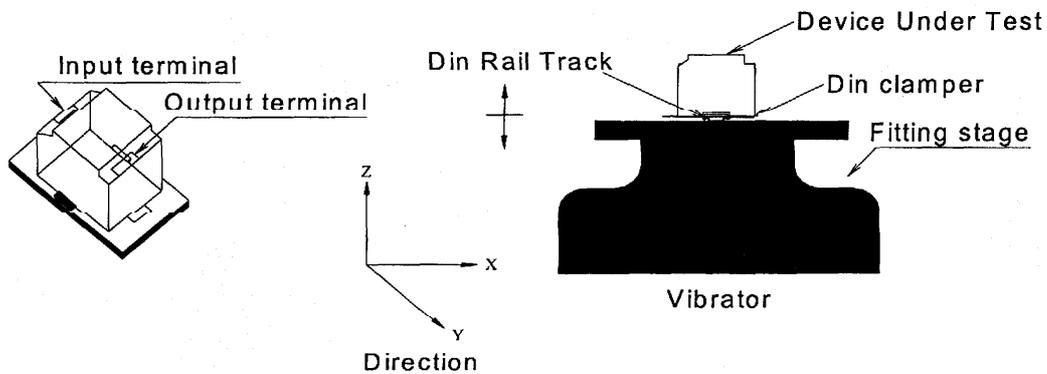
(2) Equipment Used

- Controller : DP550 (DP CORP. USA)
- Vibrator : V870 (LDS CORP. UK)

(3) Test Conditions

- Sweep frequency 10 ~ 55Hz
- Sweep time 1.0 min.
- Acceleration Constant 9.8m/s² (1G)
- Direction X, Y, Z.
- Test time 1 hour each

(4) Test Method



(5) Test Results

OK

Vin : 100VAC

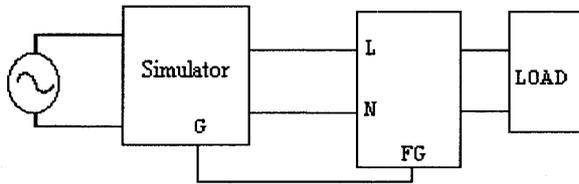
Iout : 100%

Check item		Output Voltage (V)	Ripple Voltage (mVp-p)	D.U.T.State
Before Test		24.015	40	————
After Test	X	24.018	38	O.K.
	Y	24.020	38	O.K.
	Z	24.019	38	O.K.

7. NOISE SIMULATE TEST

MODEL : DLP120-24-1

(1) Test Circuit And Equipment



Simulator : INS-400L Noise Laboratory Co.,LTD

(2) Test Conditions

- | | | | |
|-----------------------|-----------------|------------------|--------------------|
| • Input Voltage | : 100, 230VAC | • Noise Level | : 0V~2kV |
| • Output Voltage | : Rated | • Phase Shift | : 0° ~ 360° |
| • Output Current | : 0%, 100% | • Polarity | : + , - |
| • Ambient Temperature | : 25°C | • Mode | : Normal
Common |
| • Pulse Width | : 50ns ~ 1000ns | • Trigger Select | : Line |

(3) Acceptable Conditions

1. Not to be broken.
2. Not to be shut down output.
3. No other out of orders.

(4) Test Result

OK

8. THERMAL SHOCK TEST

MODEL : DLP120-24-1

(1) Equipment Used

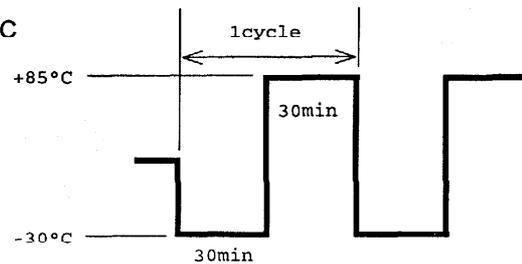
THERMAL SHOCK CHAMBER TSV-40 (TABAI ESPEC CORP.)

(2) The Number of D.U.T.(Device Under Test)

2 units

(3) Test Conditions

- Ambient Temperature : $-30^{\circ}\text{C} \longleftrightarrow 85^{\circ}\text{C}$
- Test Time : Refer to drawing
- Test Cycle : 100 Cycles
- Not Operating



(4) Test Method

Before testing, check if there is no abnormal output, then put the D.U.T. in testing chamber, and test it according to the above cycle. 100 cycles later, leave it for 1 hour at the room temperature, then check if there is no abnormal output.

(5) Test Results

OK

Vin : 100VAC			24V			
Io : 100%			FROM		TO	
Ripple Noise		mV	32		40	
Spike Noise		mV	40		50	
Line Regulation	MIN	V	23.981	0mV	23.987	3mV
	MAX	V	23.981		23.990	
Load Regulation	0%	V	24.005	28mV	24.010	23mV
	100%	V	23.977		23.987	
Efficiency	Pin	W	142.3	84.2%	144.0	83.3%
	Vout	V	23.975		23.987	
	Iout	A	5		5	
Solder Condition • etc.			—————		OK	